

CMSD6001  
 CMSD6001A  
 CMSD6001C  
 CMSD6001S

**SURFACE MOUNT  
 ULTRA LOW LEAKAGE  
 SILICON SWITCHING DIODES**



www.centrasemi.com

**SUPERmini™**



**SOT-323 CASE**

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CMSD6001 SERIES are silicon switching diodes manufactured by the epitaxial planar process, epoxy molded in a SUPERmini™ surface mount package, designed for switching applications requiring an extremely low leakage diode.

• Device is *Halogen Free* by design

**CMSD6001:** SINGLE  
**CMSD6001A:** DUAL, COMMON ANODE  
**CMSD6001C:** DUAL, COMMON CATHODE  
**CMSD6001S:** DUAL, IN-SERIES

**MARKING CODE: 6C1**  
**MARKING CODE: 61A**  
**MARKING CODE: 61C**  
**MARKING CODE: 61S**

**MAXIMUM RATINGS:** (T<sub>A</sub>=25°C)

Continuous Reverse Voltage  
 Peak Repetitive Reverse Voltage  
 Continuous Forward Current  
 Peak Repetitive Forward Current  
 Peak Forward Surge Current, tp=1.0µs  
 Peak Forward Surge Current, tp=1.0s  
 Power Dissipation  
 Operating and Storage Junction Temperature  
 Thermal Resistance

**SYMBOL**

V<sub>R</sub> 75  
 V<sub>RRM</sub> 100  
 I<sub>F</sub> 250  
 I<sub>FRM</sub> 250  
 I<sub>FSM</sub> 4.0  
 I<sub>FSM</sub> 1.0  
 P<sub>D</sub> 275  
 T<sub>J</sub>, T<sub>stg</sub> -65 to +150  
 Θ<sub>JA</sub> 455

**UNITS**

V  
 V  
 mA  
 mA  
 A  
 A  
 mW  
 °C  
 °C/W

**ELECTRICAL CHARACTERISTICS PER DIODE:** (T<sub>A</sub>=25°C unless otherwise noted)

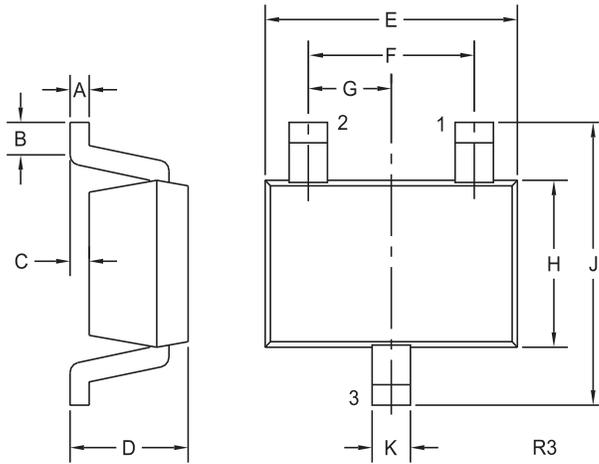
| SYMBOL          | TEST CONDITIONS  | MIN | MAX  | UNITS |
|-----------------|--|-----|------|-------|
| I <sub>R</sub>  | V <sub>R</sub> =75V  |     | 500  | pA    |
| BV <sub>R</sub> | I <sub>R</sub> =100µA  | 100 |      | V     |
| V <sub>F</sub>  | I <sub>F</sub> =1.0mA  |     | 0.85 | V     |
| V <sub>F</sub>  | I <sub>F</sub> =10mA   |     | 0.95 | V     |
| V <sub>F</sub>  | I <sub>F</sub> =100mA  |     | 1.1  | V     |
| C <sub>T</sub>  | V <sub>R</sub> =0, f=1.0MHz  |     | 2.0  | pF    |
| t <sub>rr</sub> | I <sub>R</sub> =I <sub>F</sub> =10mA, I <sub>rr</sub> =1.0mA, R <sub>L</sub> =100Ω |     | 3.0  | µs    |

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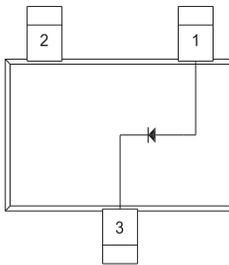
**SOT-323 CASE - MECHANICAL OUTLINE**



| SYMBOL | DIMENSIONS |       |             |      |
|--------|------------|-------|-------------|------|
|        | INCHES     |       | MILLIMETERS |      |
|        | MIN        | MAX   | MIN         | MAX  |
| A      | 0.002      | 0.008 | 0.05        | 0.20 |
| B      | 0.004      | -     | 0.10        | -    |
| C      | -          | 0.004 | -           | 0.10 |
| D      | 0.031      | 0.043 | 0.80        | 1.10 |
| E      | 0.071      | 0.087 | 1.80        | 2.20 |
| F      | 0.051      |       | 1.30        |      |
| G      | 0.026      |       | 0.65        |      |
| H      | 0.045      | 0.053 | 1.15        | 1.35 |
| J      | 0.079      | 0.087 | 2.00        | 2.20 |
| K      | 0.008      | 0.016 | 0.20        | 0.40 |

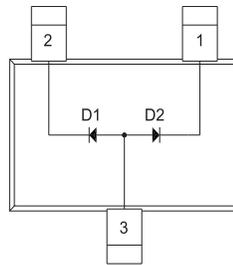
SOT-323 (REV: R3)

**PIN CONFIGURATIONS**



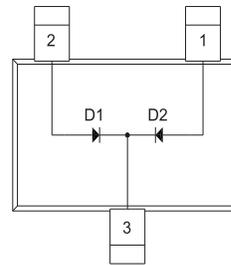
**CMSD6001**  
**LEAD CODE:**  
 1) Anode  
 2) NC  
 3) Cathode

**MARKING CODE: 6C1**



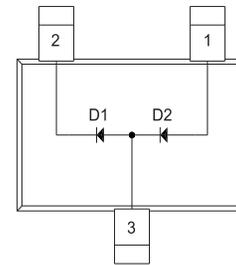
**CMSD6001A**  
**LEAD CODE:**  
 1) Cathode D2  
 2) Cathode D1  
 3) Anode D1, D2

**MARKING CODE: 61A**



**CMSD6001C**  
**LEAD CODE:**  
 1) Anode D2  
 2) Anode D1  
 3) Cathode D1, D2

**MARKING CODE: 61C**



**CMSD6001S**  
**LEAD CODE:**  
 1) Anode D2  
 2) Cathode D1  
 3) Anode D1, Cathode D2

**MARKING CODE: 61S**

R3 (9-May 2011)